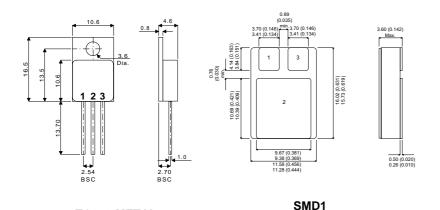


BYV32-50M BYV32-100M BYV32-150M BYV32-200M

### MECHANICAL DATA

Dimensions in mm



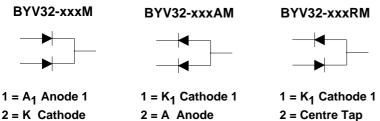
### **ELECTRICAL CONNECTIONS**

**TO220 METAL** 

3 = A<sub>2</sub> Anode 2

#### **Common Cathode Common Anode Series Connection**

**CERAMIC SURFACE MOUNT** 



3 = K<sub>2</sub> Cathode 2

# **DUAL FAST RECOVERY** SILICON RECTIFIER FOR HI-REL APPLICATIONS

HERMETICALLY SEALED

- STANDARD (COMMON CATHODE)
- COMMON ANODE
- SERIES CONNECTION

### **FEATURES**

- HERMETIC TO220 METAL OR CERAMIC SURFACE MOUNT PACKAGE
- SCREENING OPTIONS AVAILABLE
- ALL LEADS IOLATED FROM CASE
- VOLTAGE RANGE 50 TO 200V
- AVERAGE CURRENT 20A
- VERY LOW REVERSE RECOVERY TIME  $t_{rr} = 35ns$
- VERY LOW SWITCHING LOSSES

Applications include secondary rectification in high frequency switching power supplies.

			BYV32	BYV32	BYV32	BYV32	
<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>case</sub> = 25°C unless otherwise stated)		-50M	-100M	-150M	-200M		
$V_{RRM}$	Peak Repetitive Reverse Voltage		50V	100V	150V	200V	
$V_{RWM}$	Working Peak Reverse Voltage		50V	100V	150V	200V	
$V_R$	Continuous Reverse Voltage		50V	100V	150V	200V	
$I_{FRM}$	Repetitive Peak Forward Current	$t_p = 10\mu s$	200A				
$I_{F(AV)}$	Average Forward Current	$T_{case} = 70^{\circ}C$	20A				
	(switching operation, $\delta$ = 0.5, both diodes conducting)						
$I_{FSM}$	Surge Non Repetitive Forward Current $t_p = 10 \text{ ms}$		80A				
$T_{stg}$	Storage Temperature Range		–65 to 200°C				
$T_j$	Maximum Operating Junction Temperature		200°C				

 $3 = A_2$  Anode

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BYV32-50M BYV32-100M BYV32-150M BYV32-200M

## **ELECTRICAL CHARACTERISTICS** (Per Diode) (T<sub>case</sub> = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
I	Reverse Current	$V_R = V_{RWM}$	T <sub>j</sub> = 25°C			30	μΑ
I <sub>R</sub>	Reverse Current	$V_R = V_{RWM}$	T <sub>j</sub> = 100°C			0.6	mA
		I <sub>F</sub> = 8A	T <sub>C</sub> = 25°C			1.1	
V <sub>F</sub> *	Forward Voltage	I <sub>F</sub> = 20A	$T_C = 25^{\circ}C$			1.5	V
		I <sub>F</sub> = 5A	T <sub>C</sub> = 100°C			0.95	
t <sub>rr</sub>		I <sub>F</sub> = 2A	V <sub>R</sub> = 30V			35	no
	Dayaraa Dagayar / Tima	di / dt = 20A/μs				35	ns
	Reverse Recovery Time	I <sub>F</sub> = 1A	V <sub>R</sub> = 30V			50	no
		di / dt = 50A/μs				50	ns
Q <sub>rr</sub>	Recovered Charge	I <sub>F</sub> = 2A	V <sub>R</sub> = 30V			15	200
		di / dt = 20A/μs				15	nC
V <sub>FP</sub>	Forward Recovery Overvoltage	di / dt = 10A/μs	I <sub>F</sub> = 1A	1	1.0		V

<sup>\*</sup> Pulse Test:  $t_p \le 300 \mu s$ , duty cycle  $\le 2\%$ .

## THERMAL CHARACTERISTICS (TO220 METAL CASE)

$R_{\theta JC}$ †	Thermal Resistance Junction – Case			1.6	°C/W	
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<sup>†</sup> Both diodes conducting.

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